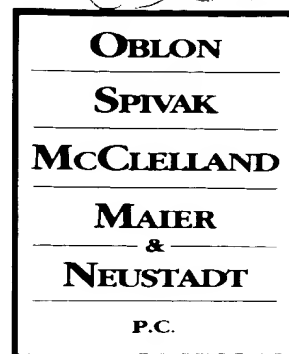




Docket No.: 209291US0



ATTORNEYS AT LAW
NORMAN F. OBLON
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ASSISTANT COMMISSIONER FOR PATENTS
WASHINGTON, D.C. 20231

RE: Application Serial No.: 09/867,467
Applicant(s): Hiroyuki NAGASAWA, ET AL.
Filing Date: May 31, 2001
For: METHOD OF MANUFACTURING SILICON CARBIDE, SILICON
CARBIDE, COMPOSITE MATERIAL, AND SEMICONDUCTOR
ELEMENT
Group No.: 2811

SIR:

Attached hereto for filing are the following papers:
LETTER TO THE OFFICIAL DRAFTSMAN
SEVEN (7) SHEETS OF FORMAL DRAWINGS FOR FIGS. 1, 2, 3A -3D, 4, 5, 6, 7, 8, 9,
10, 11 & 12.

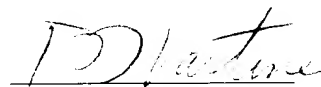
Our check in the amount of \$-0- is enclosed covering any required fees. In the event of any
variance between the amount enclosed and the Patent Office charges, please charge or credit the
difference to our Deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,
MAIER & NEUSTADT, P.C.



22850


Norman F. Oblon
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Registration No. 27,013

DOCKET NO: 209291US0



IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF: : GROUP: 2811
Hiroyuki NAGASAWA, ET AL.

SERIAL NO: 09/867,467

FILED: May 31, 2001

FOR: METHOD OF MANUFACTURING SILICON CARBIDE, SILICON CARBIDE,
COMPOSITE MATERIAL, AND SEMICONDUCTOR ELEMENT

LETTER TO OFFICIAL DRAFTSMAN

ASSISTANT COMMISSIONER FOR PATENTS
WASHINGTON, D.C. 20231

SIR:

It is requested that the enclosed SEVEN (7) sheets of Formal Drawings for FIGS. 1, 2, 3A - 3D, 4, 5, 6, 7, 8, 9, 10, 11 & 12 be entered to replace the Informal Drawings originally filed with the application.



22850

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,
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